



# UPGE10N60

## Insulated Gate Bipolar Transistor

### 600V, SMPS N-CHANNEL IGBT

■ DESCRIPTION

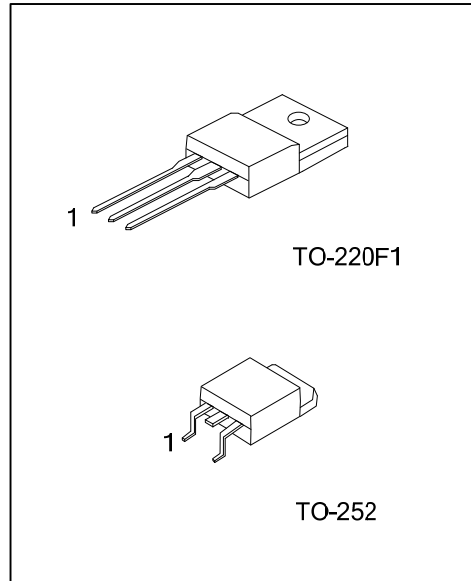
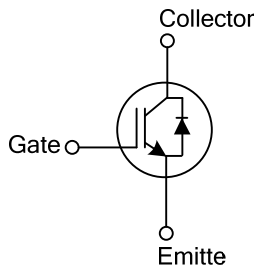
The UTC **UPGE10N60** is a N-channel IGBT. it uses UTC's advanced technology to provide customers with high input impedance, high switching speed and low conduction loss, etc.

The UTC **UPGE10N60** is suitable for high voltage switching, high frequency switch mode power supplies.

■ FEATURES

- \*  $V_{CE(SAT)} \leq 1.95V @ I_C=20A, V_{GE}=15V$
- \* High switching speed
- \* High input impedance
- \* Low conduction loss

■ SYMBOL



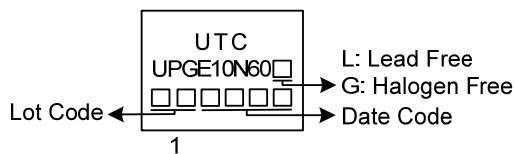
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UPGE10N60L-TF1-T	UPGE10N60G-TF1-T	TO-220F1	G	C	E	Tube
UPGE10N60L-TN3-R	UPGE10N60G-TN3-R	TO-252	G	C	E	Tape Reel

Note: Pin Assignment: G: Gate C: Collector E: Emitter

<p>UPGE10N60G-TF1-T</p>	<p>(1) T: Tube, R: Tape Reel</p> <p>(2) TF1: TO-220F1, TN3: TO-252</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_C=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	$V_{CES}$	600	V
Gate to Emitter Voltage Continuous	$V_{GES}$	$\pm 20$	V
Continuous Collector Current	$T_C=25^{\circ}\text{C}$	20	A
	$T_C=100^{\circ}\text{C}$	10	A
Collector Current Pulsed (Note 2)	$I_{CM}$	30	A
Continuous Forward Current	$T_C=25^{\circ}\text{C}$	10	A
	$T_C=100^{\circ}\text{C}$	5	A
Forward Current Pulsed	$I_{FM}$	80	A
Peak Diode Recovery $dv/dt$ (Note 3)	$dv/dt$	6.8	V/ns
Power Dissipation	TO-220F1	28	W
	TO-252	40	W
Junction Temperature	$T_J$	$-55 \sim +150$	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	$-55 \sim +150$	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3.  $I_F \leq 10\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{CC} \leq BV_{CES}$ , Starting  $T_J=25^{\circ}\text{C}$

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	TO-220F1	4.46	$^{\circ}\text{C}/\text{W}$
	TO-252	3.12	$^{\circ}\text{C}/\text{W}$

■ ELECTRICAL CHARACTERISTICS ( $T_J=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
<b>OFF CHARACTERISTICS</b>							
Collector-Emitter Breakdown Voltage	$BV_{CES}$	$I_C=250\mu\text{A}$ , $V_{GE}=0\text{V}$	600			V	
Collector-Emitter Leakage Current	$I_{CES}$	$V_{CE}=600\text{V}$ , $V_{GE}=0\text{V}$			10	$\mu\text{A}$	
Gate to Emitter Leakage Current	$I_{GES}$	$V_{CE}=0\text{V}$ , $V_{GE}=\pm 20\text{V}$			$\pm 400$	nA	
<b>ON CHARACTERISTICS</b>							
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=10\text{A}$ , $V_{GE}=15\text{V}$	$T_J=25^{\circ}\text{C}$		1.6	1.95	V
			$T_J=150^{\circ}\text{C}$		1.7		V
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	$I_C=250\mu\text{A}$ , $V_{CE}=V_{GE}$	4.0		6.5	V	
<b>DYNAMIC CHARACTERISTICS</b>							
Input Capacitance	$C_{IES}$	$V_{CE}=30\text{V}$ , $V_{GE}=0\text{V}$ , $f=1\text{MHz}$		418		pF	
Output Capacitance	$C_{OES}$			53		pF	
Reverse Transfer Capacitance	$C_{RES}$			8.9		pF	
<b>SWITCHING CHARACTERISTICS</b>							
Total Gate Charge	$Q_G$	$I_C=10\text{A}$ , $V_{CE}=100\text{V}$ , $V_{GE}=10\text{V}$		15		nC	
Gate-Emitter Charge	$Q_{GE}$			4.5		nC	
Gate-Collector Charge	$Q_{GC}$			6		nC	
Current Turn-On Delay Time	$t_{D(ON)}$	$I_C=10\text{A}$ , $V_{CE}=50\text{V}$ , $V_{GE}=15\text{V}$ , $R_G=10\Omega$		64		ns	
Current Rise Time	$t_R$			46		ns	
Current Turn-Off Delay Time	$t_{D(OFF)}$			56		ns	
Current Fall Time	$t_F$			45		ns	
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>							
Forward Voltage Drop	$V_{FM}$	$I_F=4\text{A}$			2.6	V	
Reverse Recovery Time	$t_{rr}$	$I_F=4\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$ , $V_{CC}=400\text{V}$		66		ns	
Reverse Recovery Charge	$Q_{rr}$			140		nC	

Note: Pulse Test: Pulse width  $\leq 50\mu\text{s}$ .

## ■ TEST CIRCUIT AND WAVEFORMS

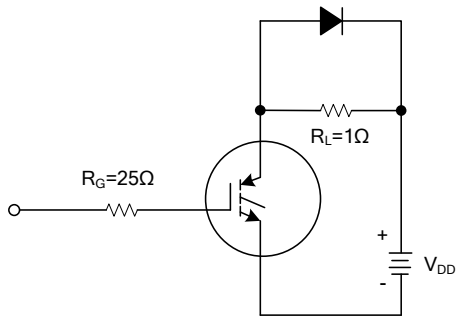


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

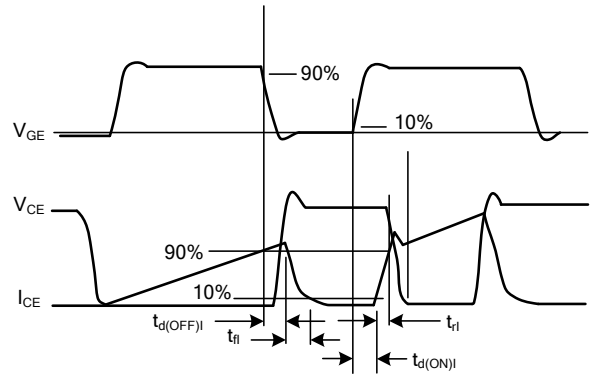
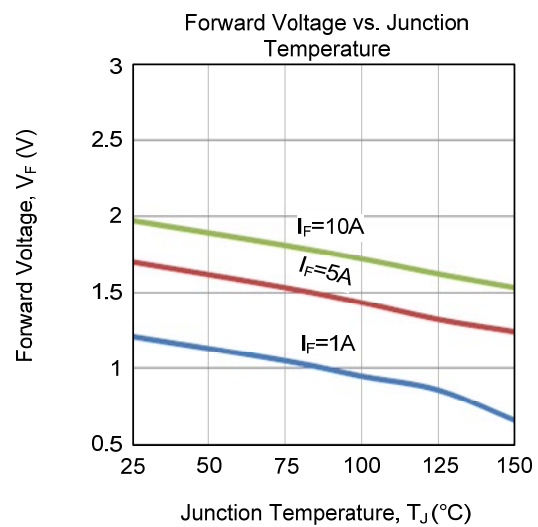
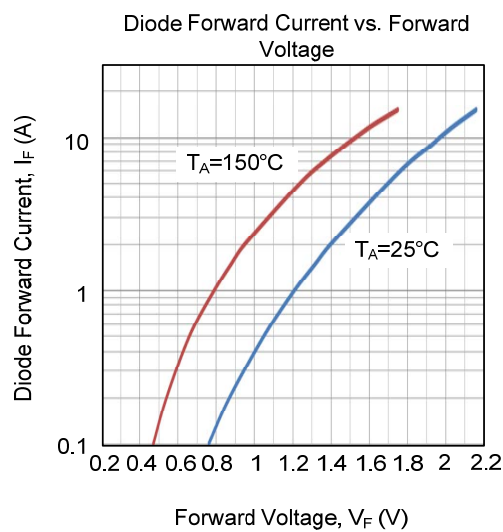
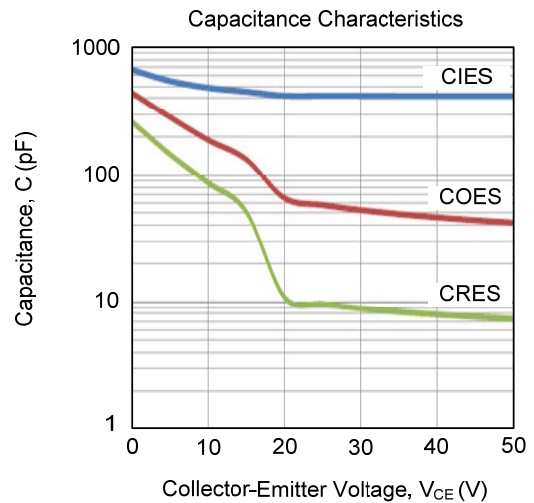
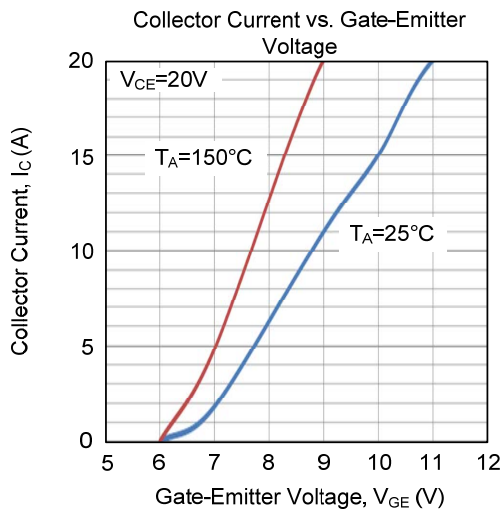
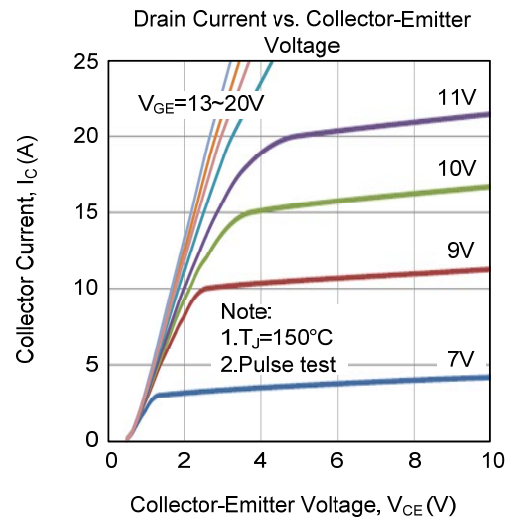
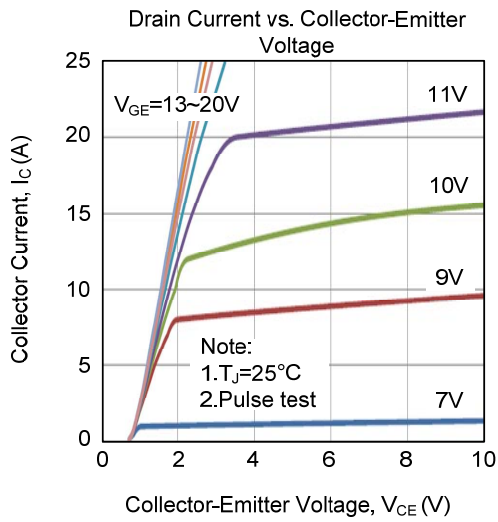
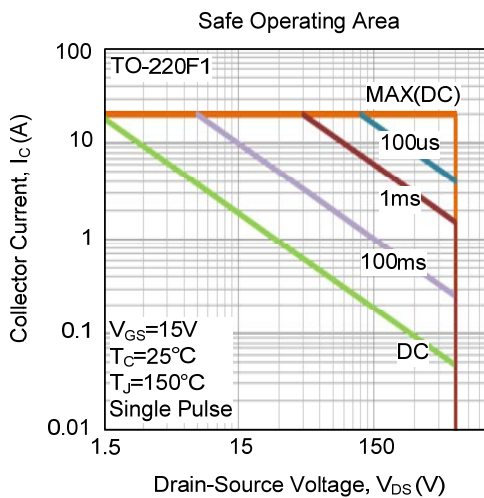
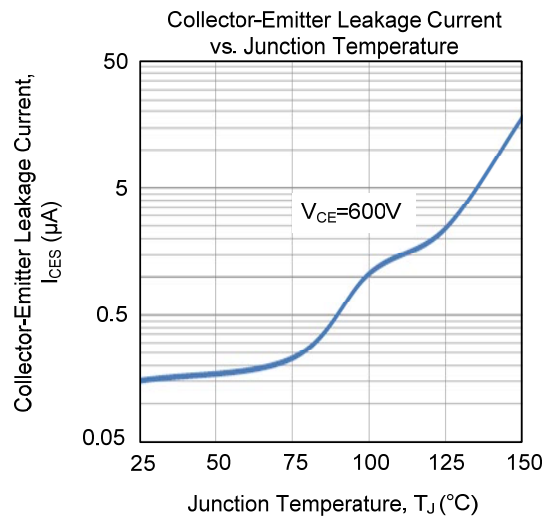
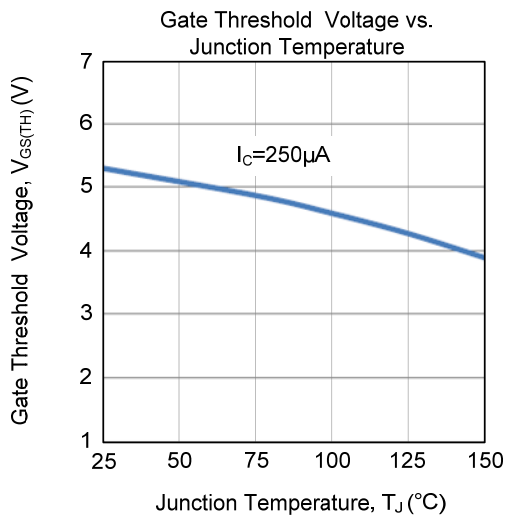
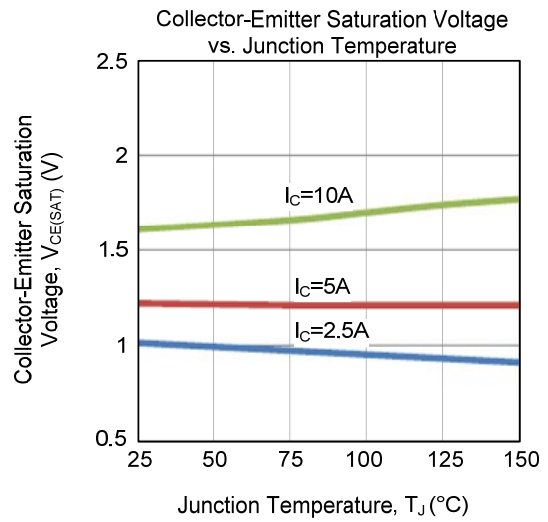
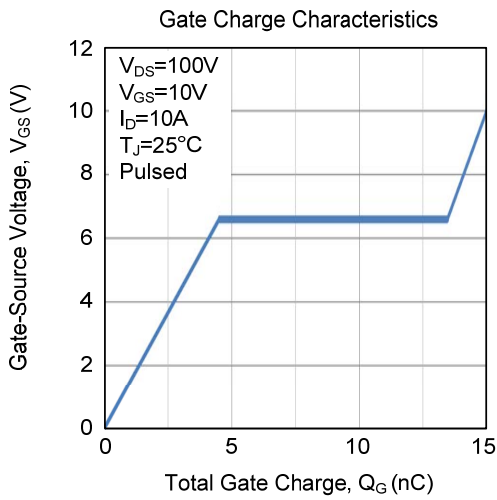


Fig 2. SWITCHING TEST WAVEFORMS

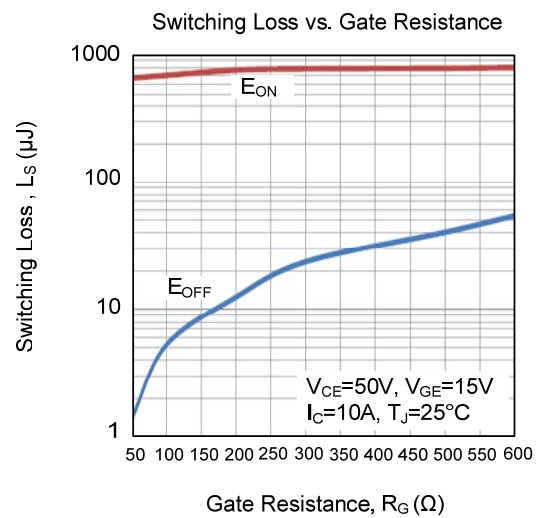
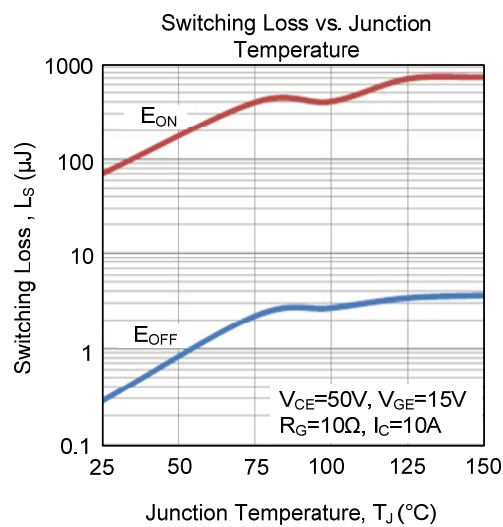
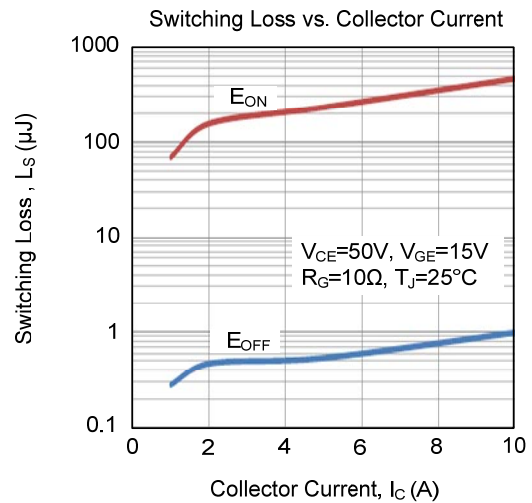
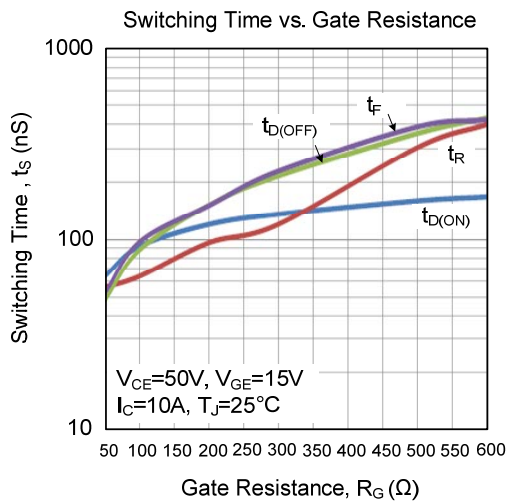
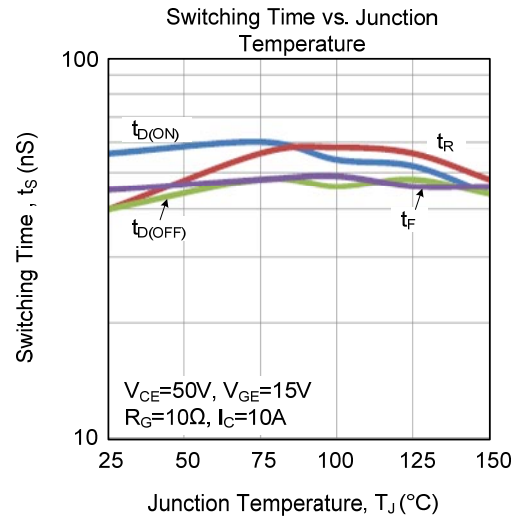
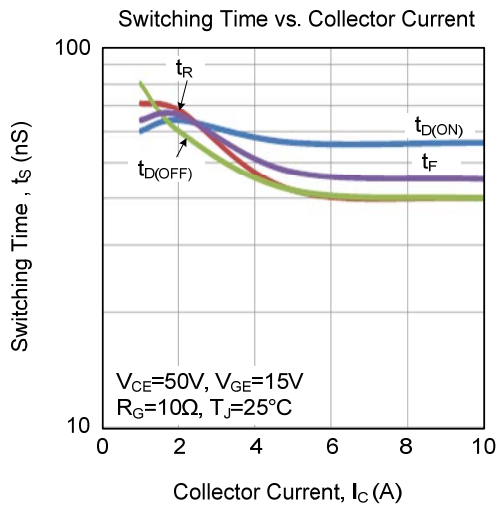
## TYPICAL CHARACTERISTICS



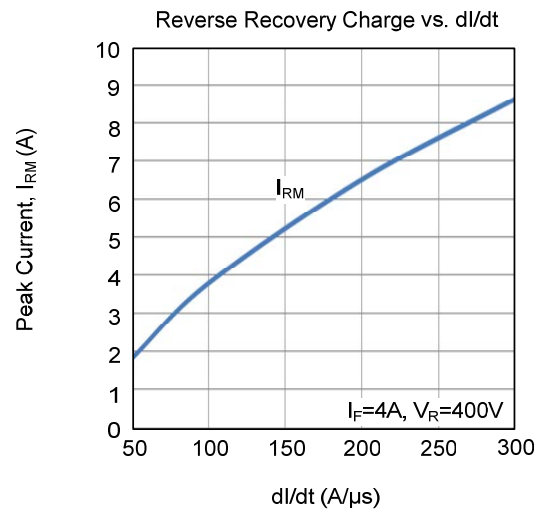
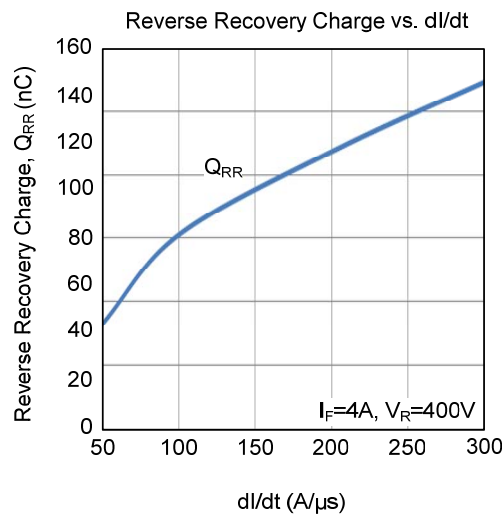
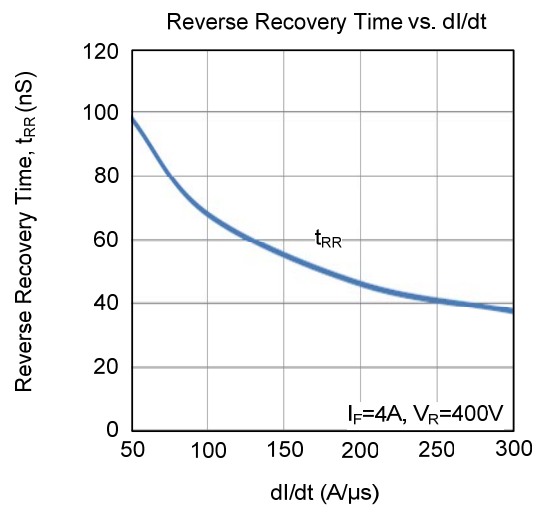
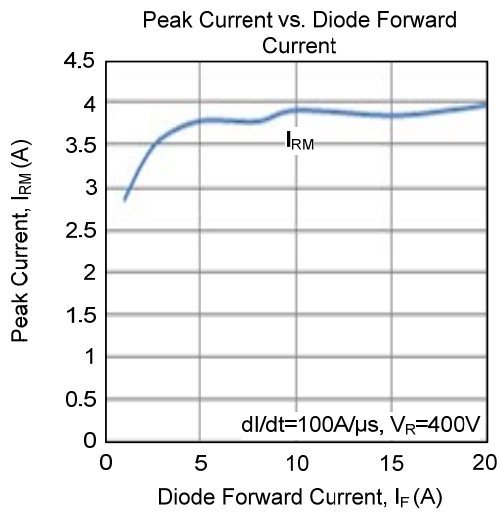
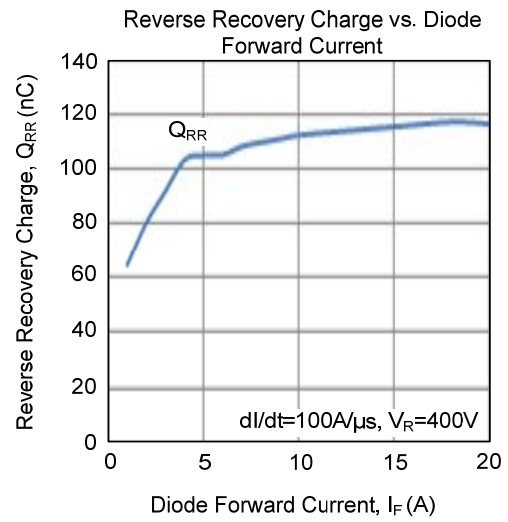
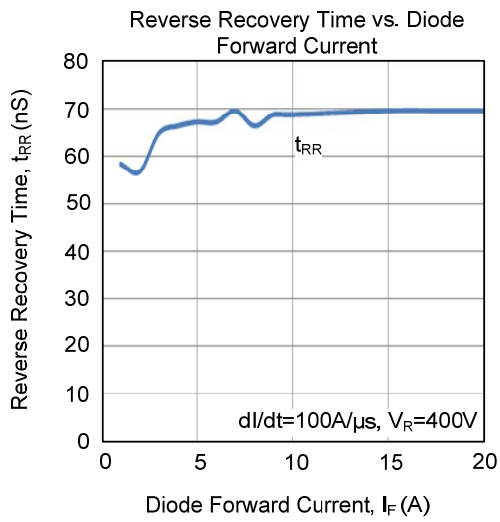
■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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